

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC573AP, TC74HC573AF

Octal D-Type Latch with 3-State Output

The TC74HC573A is a high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Its 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input ($\overline{OE}$).

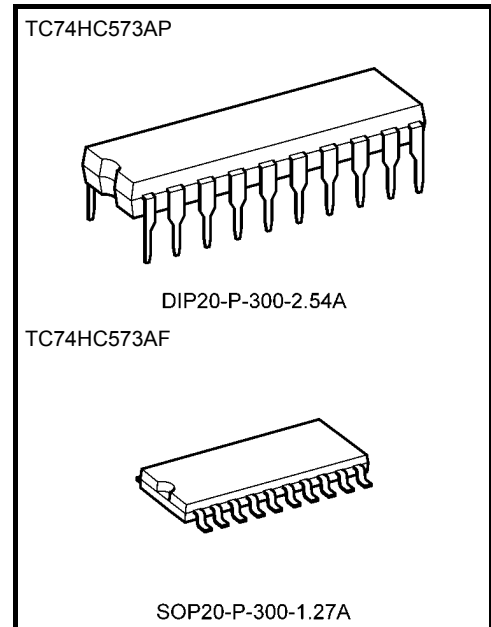
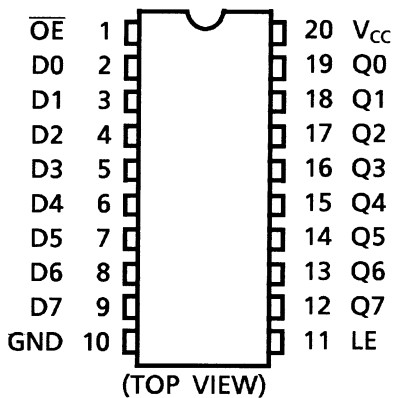
When the $\overline{OE}$ input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $t_{pd} = 13 \text{ ns}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA}$ (min)
- Balanced propagation delays: $t_{pLH} \approx t_{pHL}$
- Wide operating voltage range: $V_{CC} \text{ (opr)} = 2 \text{ to } 6 \text{ V}$
- Pin and function compatible with 74LS573

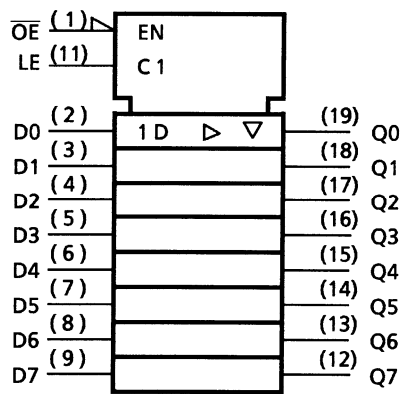
Pin Assignment



Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)

Start of commercial production
1987-11

IEC Logic Symbol



Truth Table

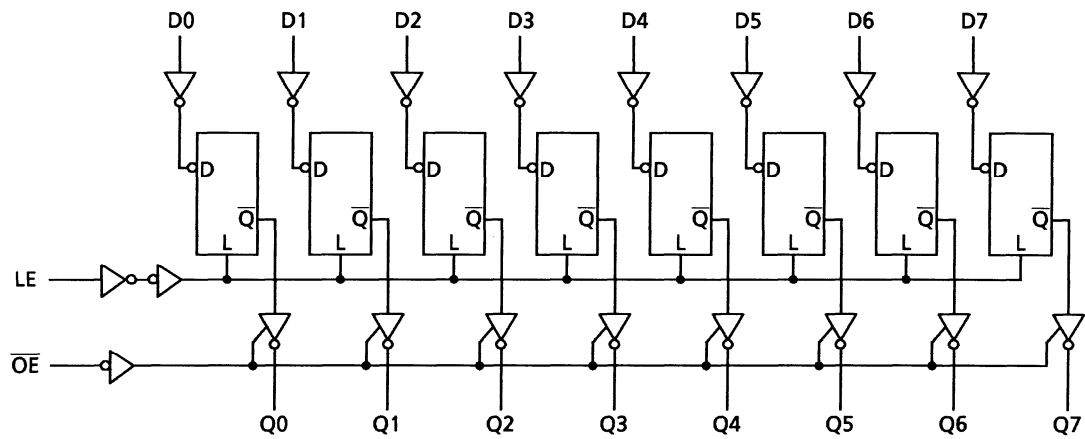
Inputs			Output
$\overline{OE}$	LE	D	Q
H	X	X	HZ
L	L	X	Qn
L	H	L	L
L	H	H	H

X: Don't care

HZ: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 35	mA
DC V_{CC} /ground current	I_{CC}	± 75	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of $-10\text{ mW}/^\circ\text{C}$ shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 ($V_{CC} = 2.0\text{ V}$) 0 to 500 ($V_{CC} = 4.5\text{ V}$) 0 to 400 ($V_{CC} = 6.0\text{ V}$)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V _{CC} (V)	Min	Typ.	Max	Min		Max
High-level input voltage	V _{IH}	—		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	V	
Low-level input voltage	V _{IL}	—		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — 1.80	V	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -6 mA I _{OH} = -7.8 mA	6.0	5.9	6.0	—	5.9	—	
				4.5 6.0	4.18 5.68	4.31 5.80	— —	4.13 5.63	— —	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
			I _{OL} = 6 mA I _{OL} = 7.8 mA	6.0	—	0.0	0.1	—	0.1	
				4.5 6.0	— —	0.17 0.18	0.26 0.26	— —	0.33 0.33	
3-state output off-state current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND		6.0	—	—	±0.5	—	±5.0	μA
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	—	—	4.0	—	40.0	μA

Timing Requirements (input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
				V _{CC} (V)	Typ.	Limit	
Minimum pulse width (LE)	t _W (H)	—		2.0	—	75	95
				4.5	—	15	19
				6.0	—	13	16
Minimum set-up time (data)	t _s	—		2.0	—	50	65
				4.5	—	10	13
				6.0	—	9	11
Minimum hold time (data)	t _h	—		2.0	—	5	5
				4.5	—	5	5
				6.0	—	5	5

AC Characteristics (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = –40 to 85°C		Unit
			CL (pF)	V _{CC} (V)	Min	Typ.	Max	Min	Max	
Output transition time	t _{TLH} t _{THL}	—	50	2.0 4.5 6.0	— — —	20 6 5	60 12 10	— — —	75 15 13	ns
Propagation delay time (LE-Q)	t _{pLH} t _{pHL}	—	50	2.0	—	50	115	—	145	ns
				4.5	—	15	23	—	29	
				6.0	—	13	20	—	25	
			150	2.0	—	60	155	—	195	
				4.5	—	20	31	—	39	
				6.0	—	17	26	—	33	
Propagation delay time (D-Q)	t _{pLH} t _{pHL}	—	50	2.0	—	42	110	—	140	ns
				4.5	—	14	22	—	28	
				6.0	—	12	19	—	24	
			150	2.0	—	57	150	—	190	
				4.5	—	19	30	—	38	
				6.0	—	16	26	—	32	
Output enable time	t _{pZL} t _{pZH}	R _L = 1 kΩ	50	2.0	—	55	140	—	175	ns
				4.5	—	17	28	—	35	
				6.0	—	14	24	—	30	
			150	2.0	—	66	180	—	225	
				4.5	—	22	36	—	45	
				6.0	—	19	31	—	38	
Output disable time	t _{pLZ} t _{pHZ}	R _L = 1 kΩ	50	2.0	—	40	125	—	155	ns
				4.5	—	17	25	—	31	
				6.0	—	15	21	—	26	
Input capacitance	C _{IN}	—			—	5	10	—	10	pF
Output capacitance	C _{OUT}	—			—	10	—	—	—	pF
Power dissipation capacitance	C _{PD} (Note)	—			—	51	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per latch)}$$

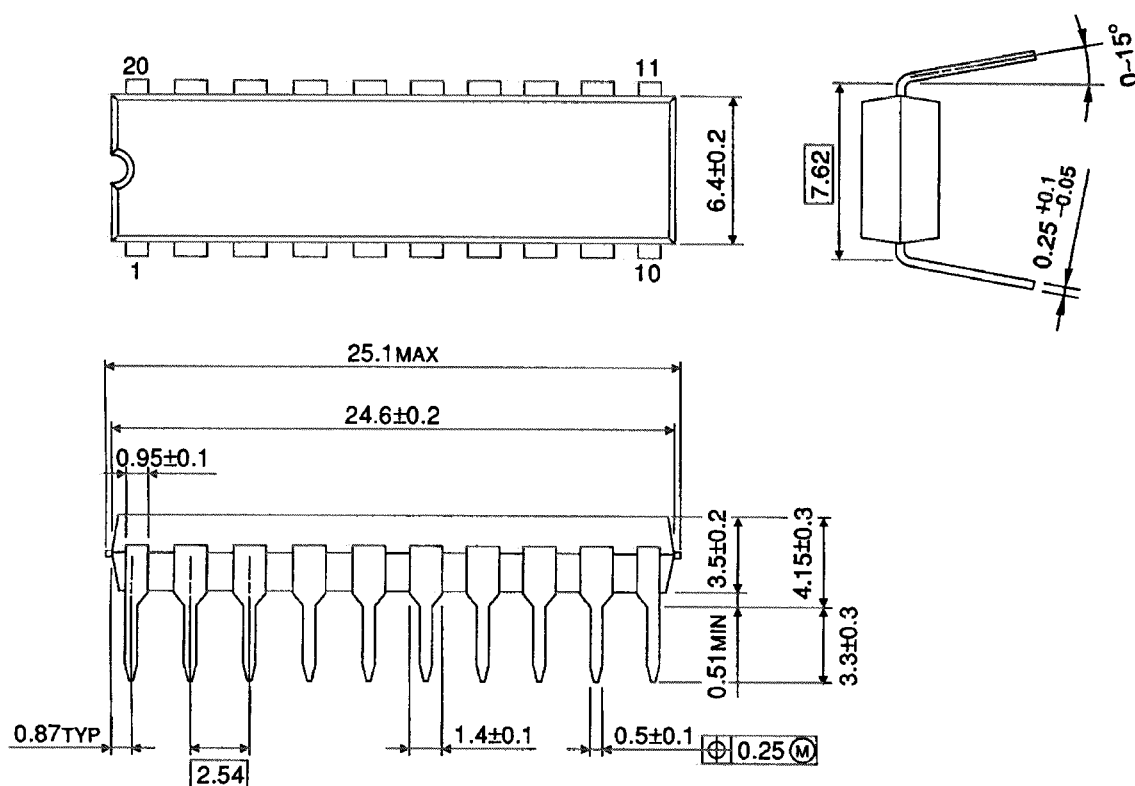
And the total C_{PD} when n pcs. of latch operate can be gained by the following equation:

$$C_{PD}(\text{total}) = 33 + 18 \cdot n$$

Package Dimensions

DIP20-P-300-2.54A

Unit : mm

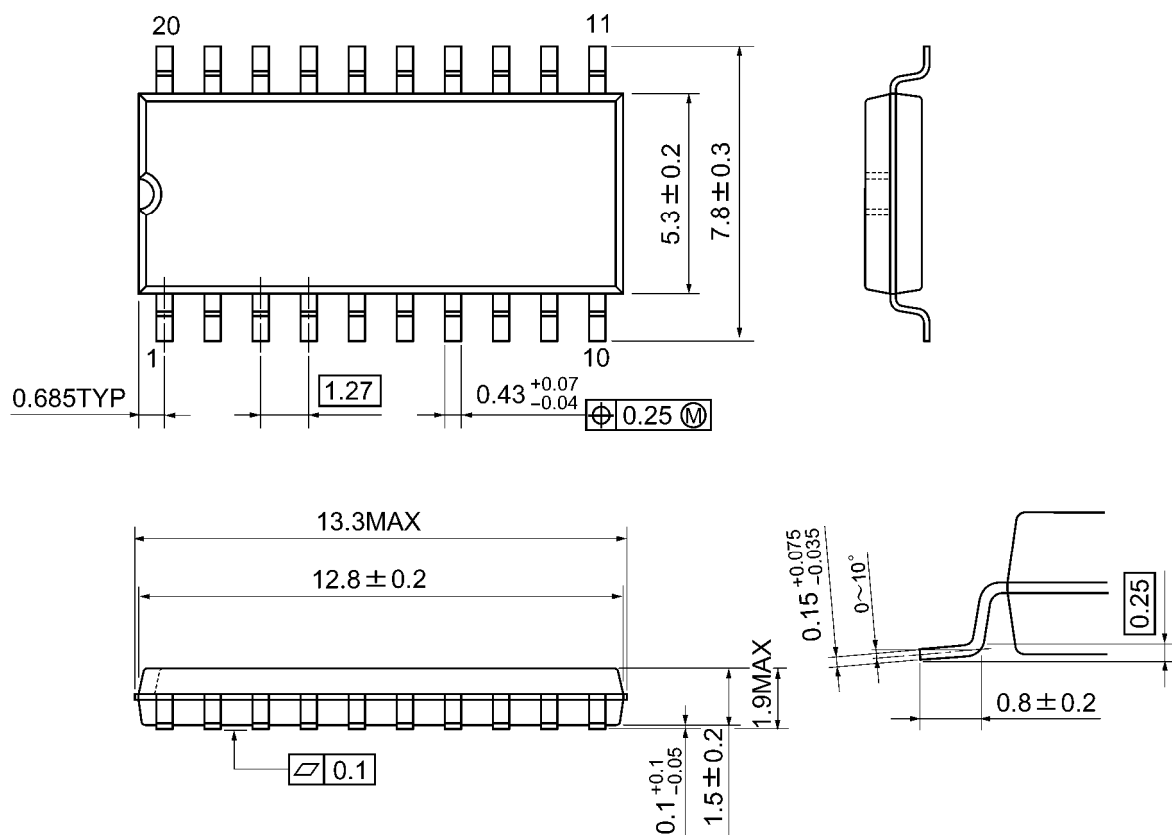


Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A

Unit: mm



Weight: 0.22 g (typ.)

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